NCE P-Channel Enhancement Mode Power MOSFET

Description

The NCE9435 uses advanced trench technology to provide excellent $R_{\rm DS(ON)}$, low gate charge and operation with gate voltages as low as 4.5V. This device is suitable for use as a load switch or in PWM applications.

General Features

• $V_{DS} = -30V, I_D = -5.1A$

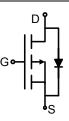
 $R_{DS(ON)}$ < 90m Ω @ V_{GS} =-4.5V

 $R_{DS(ON)}$ < 55m Ω @ V_{GS} =-10V

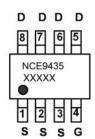
- High Power and current handing capability
- Lead free product is acquired
- Surface Mount Package

Application

- PWM applications
- Load switch
- Power management



Schematic diagram



Marking and pin Assignment



SOP-8 top view

Package Marking and Ordering Information

Device Marking	Device	Device Package	Reel Size	Tape width	Quantity
NCE9435	NCE9435	SOP-8	Ø330mm	12mm	4000 units

Absolute Maximum Ratings (T_A=25℃unless otherwise noted)

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Parameter	Symbol	Limit	Unit		
Drain-Source Voltage	V _{DS}	-30	V		
Gate-Source Voltage	V _G s	±20	V		
Drain Current-Continuous	I _D	-5.1	Α		
Drain Current-Pulsed (Note 1)	I _{DM}	-20	Α		
Maximum Power Dissipation	P _D	2.5	W		
Operating Junction and Storage Temperature Range	T_{J}, T_{STG}	-55 To 150	$^{\circ}$		

Thermal Characteristic

Thermal Resistance, Junction-to-Ambient (Note 2)	$R_{ heta JA}$	50	°C/W
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Electrical Characteristics (T_A=25°C unless otherwise noted)

Parameter	Symbol	Condition	Min	Тур	Max	Unit
Off Characteristics						
Drain-Source Breakdown Voltage	BV _{DSS}	V _{GS} =0V I _D =-250μA	-30	-33	-	V



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Zero Gate Voltage Drain Current	I _{DSS}	V _{DS} =-24V,V _{GS} =0V	-	-	-1	μA
Gate-Body Leakage Current	I _{GSS}	V _{GS} =±20V,V _{DS} =0V	-	-	±100	nA
On Characteristics (Note 3)						
Gate Threshold Voltage	V _{GS(th)}	V _{DS} =V _{GS} ,I _D =-250μA	-1.1	-1.6	-2.1	V
Drain Course On State Desigtance	D	V _{GS} =-10V, I _D =-5.1A	-	43	55	mΩ
Drain-Source On-State Resistance	R _{DS(ON)}	V _{GS} =-4.5V, I _D =-4.2A	-	62	90	mΩ
Forward Transconductance	g FS	V _{DS} =-15V,I _D =-5.1A	4	7	-	S
Dynamic Characteristics (Note4)		•				
Input Capacitance	C _{lss}	\/ - 45\/\/ -0\/	-	980	-	PF
Output Capacitance	C _{oss}	V _{DS} =-15V,V _{GS} =0V, F=1.0MHz		390	-	PF
Reverse Transfer Capacitance	C _{rss}	F-1.UIVIFIZ	-	135	-	PF
Switching Characteristics (Note 4)	·					
Turn-on Delay Time	t _{d(on)}		-	14	-	nS
Turn-on Rise Time	t _r	V _{DD} =-15V, ID=-1A,	-	12	-	nS
Turn-Off Delay Time	$t_{d(off)}$	V_{GS} =-10 V , R_{GEN} =6 Ω	-	56	-	nS
Turn-Off Fall Time	t _f			20	-	nS
Total Gate Charge	Qg		-	11	-	nC
Gate-Source Charge	Q _{gs}	V _{DS} =-15V,I _D =-5.1A,V _{GS} =-10V	-	2.0	-	nC
Gate-Drain Charge	Q _{gd}		-	2.8	-	nC
Drain-Source Diode Characteristics						
Diode Forward Voltage (Note 3)	V _{SD}	V _{GS} =0V,I _S =-5.1A	-	-	-1.2	V

Notes:

- 1. Repetitive Rating: Pulse width limited by maximum junction temperature.
- 2. Surface Mounted on FR4 Board, t ≤ 10 sec.
- 3. Pulse Test: Pulse Width ≤ 300µs, Duty Cycle ≤ 2%.
- **4.** Guaranteed by design, not subject to production



Typical Electrical and Thermal Characteristics

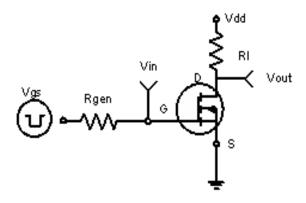


Figure 1:Switching Test Circuit

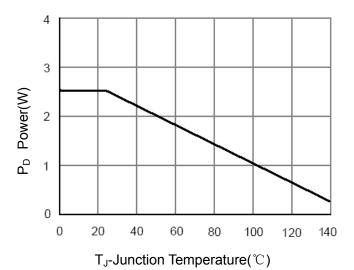


Figure 3 Power Dissipation

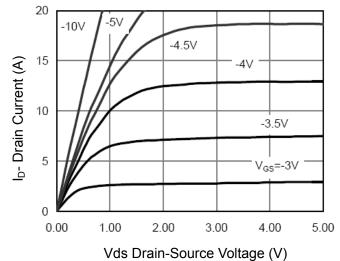


Figure 5 Output Characteristics

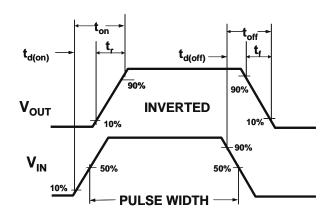


Figure 2:Switching Waveforms

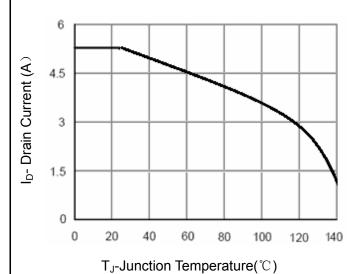


Figure 4 Drain Current

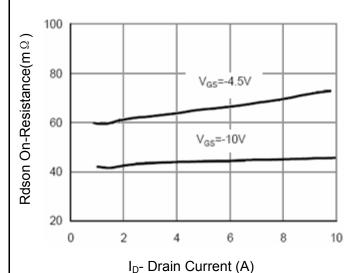


Figure 6 Drain-Source On-Resistance



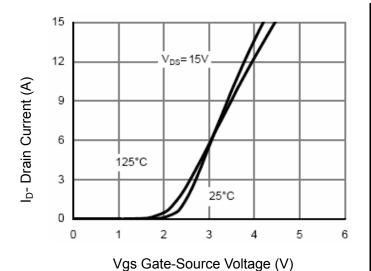


Figure 7 Transfer Characteristics

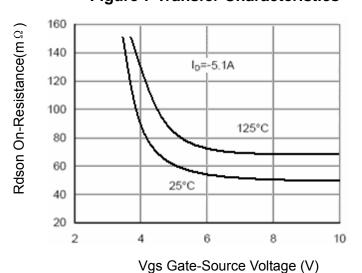


Figure 9 Rdson vs Vgs

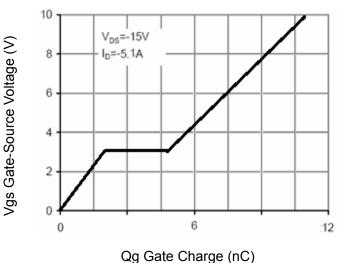


Figure 11 Gate Charge

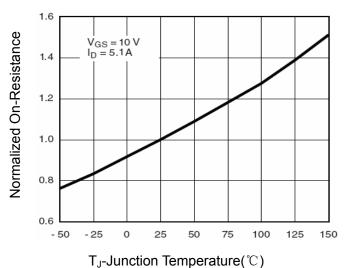
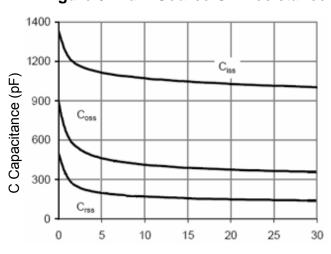


Figure 8 Drain-Source On-Resistance



Vds Drain-Source Voltage (V)

Figure 10 Capacitance vs Vds

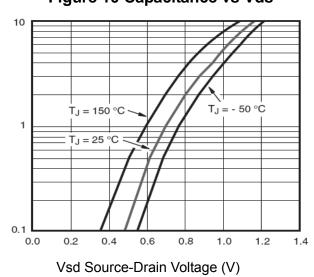


Figure 12 Source- Drain Diode Forward

Is- Reverse Drain Current (A)



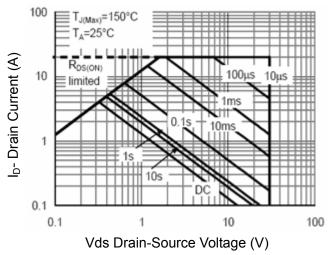


Figure 13 Safe Operation Area

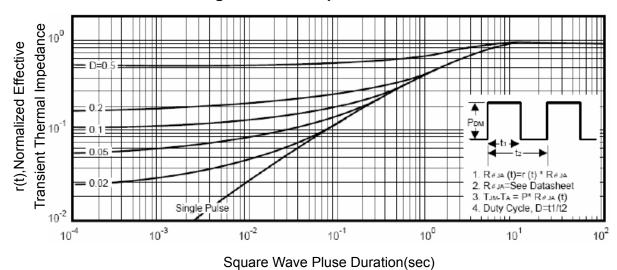
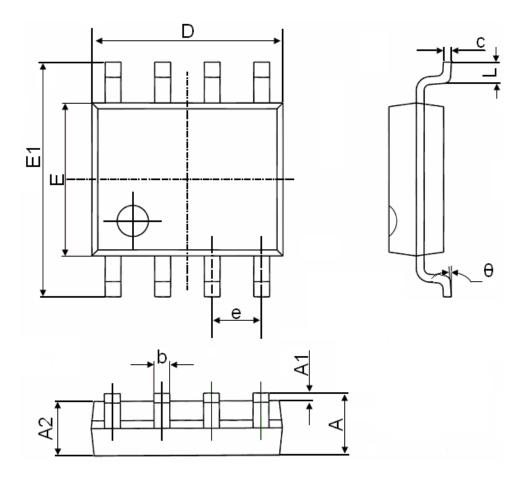


Figure 14 Normalized Maximum Transient Thermal Impedance

SOP-8 Package Information



Symbol	Dimensions	In Millimeters	Dimensions In Inches		
Symbol	Min.	Max.	Min.	Max.	
Α	1.350	1.750	0.053	0.069	
A1	0.100	0.250	0.004	0.010	
A2	1.350	1.550	0.053	0.061	
b	0.330	0.510	0.013	0.020	
С	0.170	0.250	0.006	0.010	
D	4.700	5.100	0.185	0.200	
E	3.800	4.000	0.150	0.157	
E1	5.800	6.200	0.228	0.244	
е	1.270	(BSC)	0.050	(BSC)	
L	0.400	1.270	0.016	0.050	
θ	0°	8°	0°	8°	



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